#### KING FAHD UNIVERSITY OF PETROLEUM AND MINERALS DEPARTMENT OF ELECTRICAL ENGINEERING Electronic Circuits I - EE203

# *Experiment # 6* BJT CE Amplifier

# **OBJECTIVE**

The purpose of this experiment is to:

- Demonstrate the operation and characteristics of the small signal CE amplifier.
- Determine the maximum output available from a basic common-emitter amplifier.
- Calculate voltage gain, input, and output resistance experimentally.

# **COMPONENTS REQUIRED**

- Transistor 2N3904
- Capacitors  $22\mu F$  (2No's), 100  $\mu F$
- Resistors  $50k\Omega$ ,  $22k\Omega$ ,  $3.3k\Omega$  (2No's), 2.2k



# PRELAB

- 1. For the circuit shown in Figure 2 consider  $\beta$ =75. Calculate the dc components I<sub>BQ</sub> and I<sub>CQ</sub>, V<sub>CEQ</sub>.
- 2. Draw the small signal equivalent circuit.
- 3. Calculate the voltage gain for the circuit  $(v_0/v_s)$ .
- 4. Remove  $C_E$  and calculate the voltage gain.
- 5. Connect a resistance of  $2k\Omega$  in series with the source in the presence of  $C_E$  and calculate the new voltage gain.
- 6. From 3 and 5 calculate input resistance of the amplifier.
- 7. Remove the load resistance  $R_L$  and calculate the voltage gain (in the presence of  $C_E$ ).
- 8. From 3 and 7 calculate the output resistance seen by the load

### **SUMMARY OF THEORY**

In a common-emitter (CE) amplifier, the input signal is applied between the base and emitter and output signal is developed between the collector and emitter. The transistor's *emitter* is common to both the input and output circuits, hence the term common emitter. The input and out signal gives 180° phase shift.

To amplify ac signal, the base-emitter junction must be forward biased and the base-collector junction must be reverse-biased. The bias establishes and maintains the proper dc operating conditions for the transistor. After analyzing the dc conditions, the ac parameters for the amplifier can be evaluated.

Figure 2, below shows the transistor configured as a common emitter amplifier. In this diagram,  $V_S$  is the a.c. signal source, and  $R_L$  is the load.  $V_{CC}$  is a power supply, which provides the transistor with the necessary power to amplify the a.c. signal. Resistors  $R_1$  and  $R_2$  are used to establish the correct voltage at the base of the transistor. (See the text for more details.)

The capacitors  $C_1$  and  $C_2$  serve to isolate the signal source and load from the voltage source  $V_{CC}$ . (The capacitors are called "blocking capacitors" or "coupling capacitors", since they block the d.c. voltage but act like a short to the a.c. signal.)

#### **EXPERIMENTAL WORK**

Before you connect the circuit test the transistor using DMM and curve Tracer, instructor will examine you procedure.

#### **DC** analysis

- 1. Wire the circuit as shown in Figure 2. The pin diagram for the 2N3904 transistor is shown in Figure 1.
- 2. After you have checked all connections, apply the 10V supply voltage (you have to adjust the supply of 5-15V variable from beardboard to 10V using multimeter).



3. With a multimeter, individually measure the transistor dc base, emitter and collector voltages and currents, record you results in table1. Find $\beta$ . Make sure

Parameters	Measured Value	Theoritical Value	Simulation Value
V <sub>B</sub>			
$V_{\rm E}$			
V <sub>C</sub>			
I <sub>B</sub>			
I <sub>E</sub>			
I <sub>C</sub>			

your transistor is biased in the active mode for amplifier application. Record your results in Table 1.

#### Table1

### **Small Signal Analysis**

- 4. Apply a sine wave (10mV, 100 kHz) and measure the output voltage using the double beam oscilloscope. Display both input and output signals on the oscilloscope and observe the phase shift. Measure the output voltage and compute the voltage gain. (Avoid using Autoset of the oscilloscope, adjust manually, if the display is distorted due to the use of the 20dB attenuator)
- 5. You must observe that the output signal level (V<sub>out</sub>) is greater the input signal level (V<sub>s</sub>). In addition, V<sub>out</sub> is inverted or 180 degree out-of-phase, with respect to the input. Those points are two major characteristics of a common-emitter amplifier.
- 6. Remove  $C_E$  and calculate the voltage gain.
- 7. Reconnect  $C_E$ . Connect a  $2k\Omega$  resistance ( $R_S$ ) in series with the source and calculate the voltage gain in the presence of  $C_E$ . Use the value obtained in step 2 with the one obtained here to calculate the input resistance.
- 8. Remove the load resistance and calculate the voltage gain with  $C_E$  connected. Summarize your results in Table 2.
- 9. Compare results to the theoretical calculations and PSPICE simulation. Find the error percentages and discuss the factors that caused these errors.
- 10. Attach theoretical and Pspice results with the report.
- 11. Input and Output resistance can be calculated using.

$R_i / (R_i + R_s) = A_3 / A_1$	R <sub>i</sub> Input Resistance
$R_{L}/(R_{L}+R_{O}) = A_{1}/A_{4}$	Ro Output Resistance

Record all your observations in table 2.

Ce	Rs	RL	Vs(p-p)	Vout(p-p)	Measured Gain	Theoretical gain	Simulation gain
$100\mu F$	Without	3.3K	20mV		$A_1 =$	$A_1 =$	
Without	Without	3.3K	20mV		A2=	A2=	
$100\mu F$	2K	3.3K	20mV		$A_3 =$	A3=	
$100\mu F$	Without	Without	20mV		$A_4 =$	$A_4 =$	

Table 2

### **PSPICE WORK**

#### **BIAS POINT DETAIL SIMULATION**

Use Schematics to connect the circuit shown in Figure 2. Analyze the circuit by choosing *Analysis*  $\rightarrow$  *Setup*  $\rightarrow$  *Bias Point*. Run the simulation by choosing *Simulate* from the *Analysis* menu (See the results from examine output choosing from file Menu). Write all the results in the following table.

Vcc	VB	VE	V <sub>C</sub>	IB	IE	I <sub>C</sub>	β	α

#### SMALL SIGNAL ANALYSIS

Use Schematics to draw the amplifier circuit in Figure 2. For source *Vs* use *VSIN* from the *Get New Part* Menu. Double click the source and enter the values of peak voltage and frequency of 10mV and 1 kHz. Exactly follow the same procedure used in Lab. Write all the results in Table 2.